

CSD19505KTT 80 V N-Channel NexFET[™] Power MOSFET

1 Features

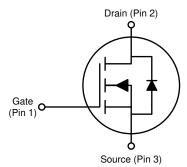
- Ultra-low Q_g and Q_{gd} Low thermal resistance
- Avalanche rated
- Pb-free terminal plating
- RoHS compliant
- Halogen free •
- D²PAK plastic package •

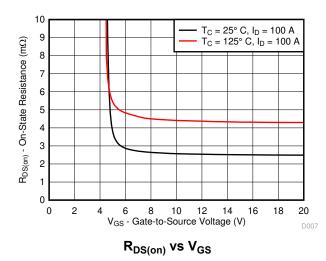
2 Applications

- Secondary side synchronous rectifier
- Motor control

3 Description

This 80V, 2.6mΩ, D²PAK (TO-263) NexFET[™] power MOSFET is designed to minimize losses in power conversion applications.





Product Summary

T _A = 25°	с	TYPICAL VA	LUE	UNIT
V _{DS}	Drain-to-Source Voltage	80		V
Qg	Gate Charge Total (10V)	76	nC	
Q _{gd}	Gate Charge Gate to Drain	11	nC	
Б	Drain-to-Source On Resistance	V _{GS} = 6V	2.9	mΩ
R _{DS(on)}	Drain-to-Source On Resistance	V _{GS} = 10V	2.6	mΩ
V _{GS(th)}	Threshold Voltage	2.6		V

Device Information (1)

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD19505KTT	500	13-Inch	D ² PAK Plastic Package	Tape &
CSD19505KTTT	50	Reel	D FAN FIASIIC FACKAGE	Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

T _A = 2	25°C	VALUE	UNIT
V _{DS}	Drain-to-Source Voltage	80	V
V _{GS}	Gate-to-Source Voltage	±20	V
	Continuous Drain Current (Package Limited)	200	Α
I _D	Continuous Drain Current (Silicon Limited), $T_C = 25^{\circ}C$	212	А
	Continuous Drain Current (Silicon Limited), $T_{C} = 100^{\circ}C$	150	А
I _{DM}	Pulsed Drain Current ⁽¹⁾	400	A
P _D	Power Dissipation	300	W
T _J , T _{stg}	Operating Junction, Storage Temperature	–55 to 175	°C
E _{AS}	Avalanche Energy, Single Pulse I_D = 101A, L = 0.1mH, R_G = 25 Ω	510	mJ

⁽¹⁾ Max $R_{\theta JC}$ = 0.5°C/W, pulse duration ≤100µs, duty cycle ≤1%.

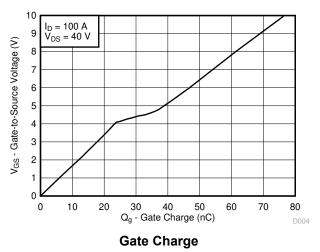




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4 Specifications

4.1 Electrical Characteristics

(T_A = 25°C unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
STATIC	CHARACTERISTICS				
BV _{DSS}	Drain-to-source voltage	V _{GS} = 0V, I _D = 250µA	80		V
I _{DSS}	Drain-to-source leakage current	V _{GS} = 0V, V _{DS} = 64V		1	μA
I _{GSS}	Gate-to-source leakage current	V _{DS} = 0V, V _{GS} = 20V		100	nA
V _{GS(th)}	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.2 2.6	3.2	V
	Duraina ta anguna ang manjatang a	V _{GS} = 6V, I _D = 100A	2.9	3.8	mΩ
R _{DS(on)}	Drain-to-source on-resistance	V _{GS} = 10V, I _D = 100A	2.6	3.1	mΩ
9 _{fs}	Transconductance	V _{DS} = 8V, I _D = 100A	262		S
DYNAM	IC CHARACTERISTICS			I	
C _{iss}	Input capacitance		6090	7920	pF
C _{oss}	Output capacitance	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	1600	2080	pF
C _{rss}	Reverse transfer capacitance		34	pF	
R _G	Series gate resistance		1.4	2.8	Ω
Qg	Gate charge total (10V)		76		nC
Q _{gd}	Gate charge gate-to-drain		11		nC
Q _{gs}	Gate charge gate-to-source	$v_{\rm DS} = 40$ V, $I_{\rm D} = 100$ A	25		nC
Q _{g(th)}	Gate charge at V _{th}	$V_{GS} = 0V, V_{DS} = 64V$ $V_{DS} = 0V, V_{GS} = 20V$ $V_{DS} = V_{GS}, I_D = 250\muA$ $V_{GS} = 6V, I_D = 100A$ $V_{GS} = 10V, I_D = 100A$ $V_{DS} = 8V, I_D = 100A$ $V_{DS} = 8V, I_D = 100A$ $V_{DS} = 40V, V_{DS} = 40V, f = 1MHz$ $V_{DS} = 40V, V_{GS} = 0V$ $V_{DS} = 40V, V_{GS} = 0V$ $V_{DS} = 40V, V_{GS} = 10V, I_{DS} = 100A, R_{G} = 0\Omega$ $I_{SD} = 100A, V_{GS} = 0V$ $V_{DS} = 40V, I_F = 100A, V_{DS} = 40V, I_F = 100A, V_{DS} = 40V, I_F = 100A, V_{DS} = 40V, V_{SS} = 10V, V_{SS} = 100A, V_{SS}$	15		nC
Q _{oss}	Output charge	V _{DS} = 40V, V _{GS} = 0V	214		nC
t _{d(on)}	Turn on delay time		11		ns
t _r	Rise time	$V_{DS} = 40V, V_{GS} = 10V,$	5		ns
t _{d(off)}	Turn off delay time	$I_{DS} = 100A, R_G = 0\Omega$	22		ns
t _f	Fall time		3		ns
DIODE	CHARACTERISTICS		J		
V _{SD}	Diode forward voltage	I _{SD} = 100A, V _{GS} = 0V	0.9	1.1	V
Q _{rr}	Reverse recovery charge	V_{DS} = 40V, I _F = 100A,	400		nC
t _{rr}	Reverse recovery time		88		ns

4.2 Thermal Information

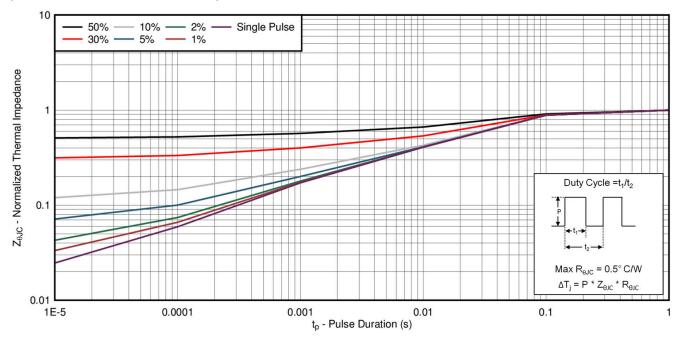
($T_A = 25^{\circ}C$ unless otherwise stated)

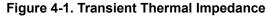
	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance			0.5	°C/W
$R_{\theta JA}$	Junction-to-ambient thermal resistance			62	°C/W

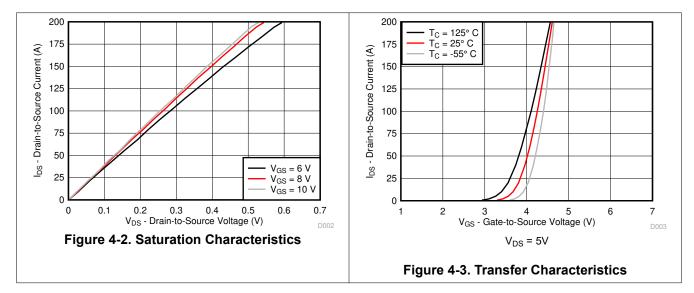


4.3 Typical MOSFET Characteristics

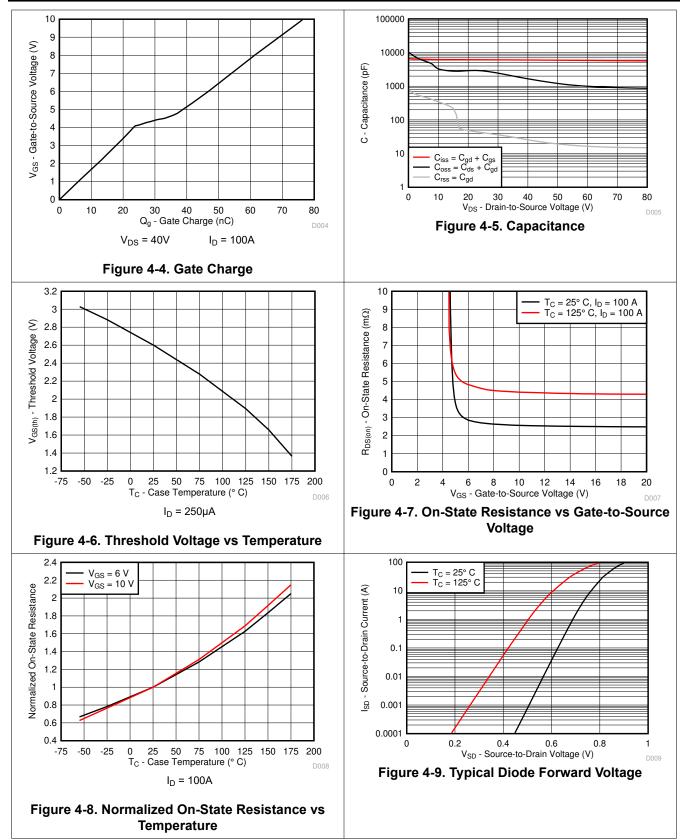
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$





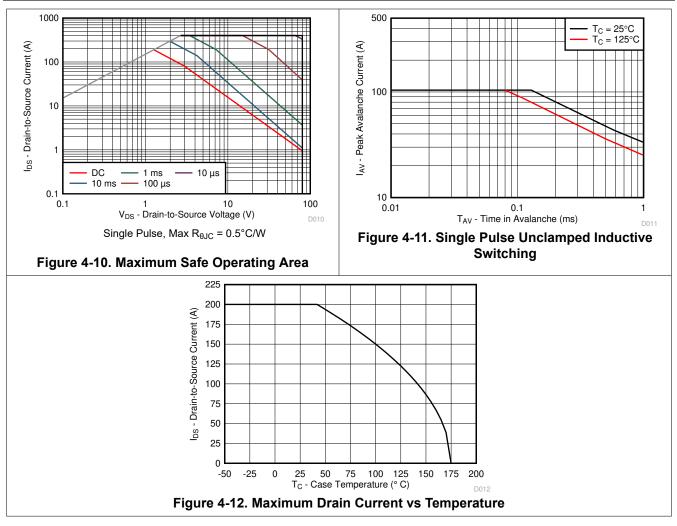








CSD19505KTT SLPS587A – MARCH 2016 – REVISED JUNE 2025





5 Device and Documentation Support

5.1 Third-Party Products Disclaimer

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5.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

5.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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5.4 Trademarks

NexFET[™] is a trademark of TI.

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5.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

5.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

6 Revision History

Changes from R	evision	n * (Ma	arch 2016) to	o Revi	sion A (June 2025)			Page
		~		~		 		



7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
CSD19505KTT	Active	Production	DDPAK/ TO-263 (KTT) 2	500 LARGE T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 175	CSD19505KTT
CSD19505KTT.B	Active	Production	DDPAK/ TO-263 (KTT) 2	500 LARGE T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 175	CSD19505KTT
CSD19505KTTT	Active	Production	DDPAK/ TO-263 (KTT) 2	50 SMALL T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 175	CSD19505KTT
CSD19505KTTT.B	Active	Production	DDPAK/ TO-263 (KTT) 2	50 SMALL T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 175	CSD19505KTT

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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PACKAGE OPTION ADDENDUM

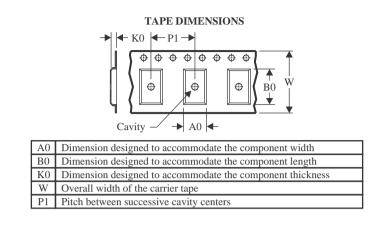
23-Jun-2025



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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD19505KTT	DDPAK/ TO-263	КТТ	2	500	330.0	24.4	10.8	16.3	5.11	16.0	24.0	Q2
CSD19505KTTT	DDPAK/ TO-263	КТТ	2	50	330.0	24.4	10.8	16.3	5.11	16.0	24.0	Q2



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PACKAGE MATERIALS INFORMATION

24-Jun-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD19505KTT	DDPAK/TO-263	КТТ	2	500	340.0	340.0	38.0
CSD19505KTTT	DDPAK/TO-263	ктт	2	50	340.0	340.0	38.0

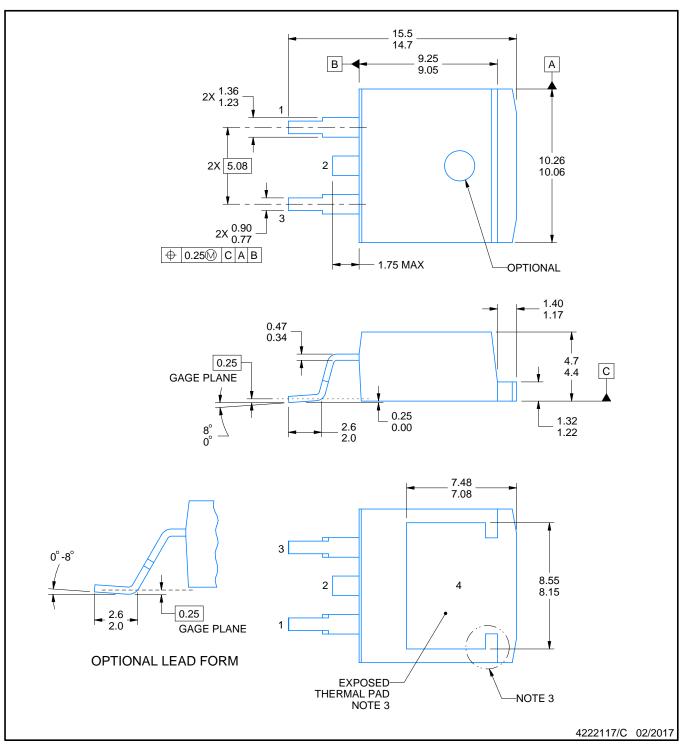
KTT0002A



PACKAGE OUTLINE

TO-263 - 4.7 mm max height

TO-263



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.
- Features may not exist and shape may vary per different assembly sites.
 Reference JEDEC registration TO-263.

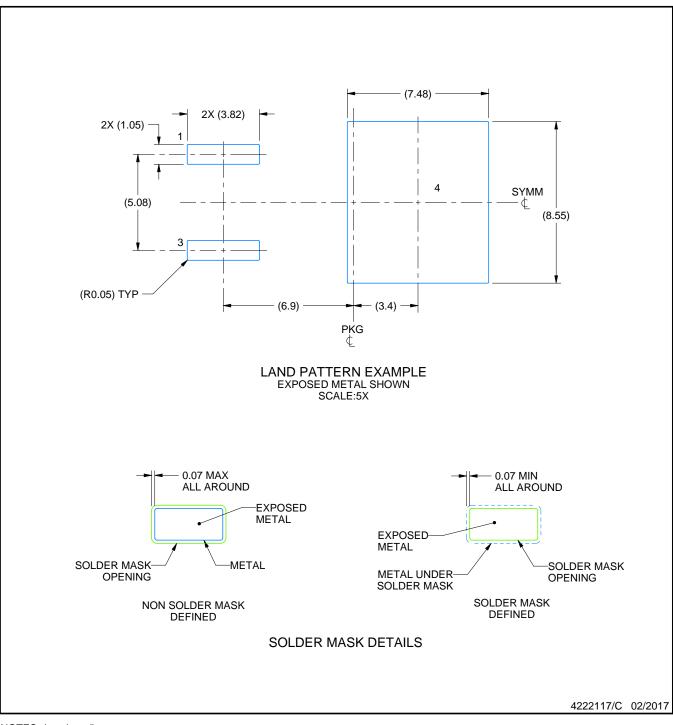


KTT0002A

EXAMPLE BOARD LAYOUT

TO-263 - 4.7 mm max height

TO-263



NOTES: (continued)

5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).

6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

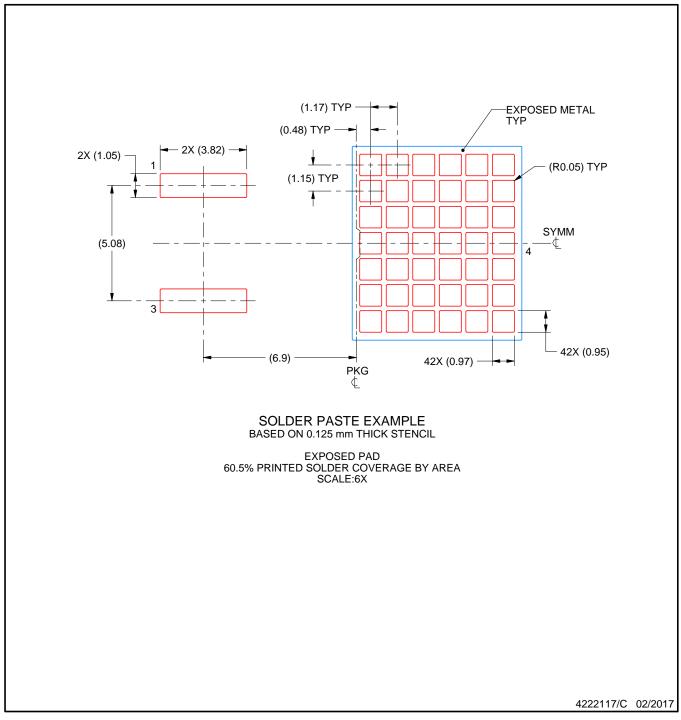


KTT0002A

EXAMPLE STENCIL DESIGN

TO-263 - 4.7 mm max height

TO-263



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations. 8. Board assembly site may have different recommendations for stencil design.



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